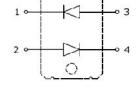


PRELIMINARY DATASHEET

Anti-Parallel 1200V 2X28A, Silicon Carbide Schottky Diode in Isolated SOT227 Package

APPLICATIONS

- > Switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)
- Induction heating
- Motor drives
- > High speed rectifiers



FEATURES

- > 175 °C maximum junction temperature
- > Extremely fast switching independent with temperature
- Positive temperature coefficient for safe operation
- > No reverse recovery
- Pb-free finished; RoHS compliant



MAXIMUM RATINGS (per Diode)

Parameter	Symbol	Value	Units	
Repetitive peak reverse voltage	V_{RRM}	1200	V	
DC forward current $T_c = 120 ^{\circ}\text{C}$	I _{F(AV)}	28		
Surge non-repetitive forward current, half sine wave $T_C = 25$ °C, $t_p = 8.3$ ms	I _{FSM}	142	A	
Operating junction and storage temperature range	T _j , T _{stg}	-55 to 175	°C	

Thermal and Isolation Characteristics

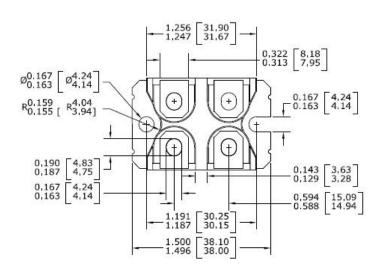
Parameter	Symbol	Max. Value	Units
Characteristics			
Thermal resistance, junction to case, per Diode	R _{thJC}	0.72	°C/W
Isolation voltage, RMS (measured between terminals and mounting base, 50-60 Hz, for 1-3 seconds)	V_{iso}	3000	٧

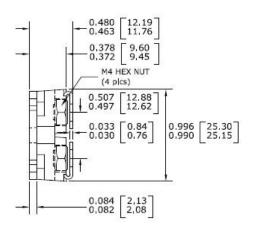
Electrical Characteristics (per Diode), at T_j = 25°C, unless otherwise specified

Parameter	Conditions	Symbol	Value			II.m.ii		
			Min.	Тур.	Max.	Unit		
Static Characteristics								
Reverse leakage current	V _R = 1200 V	I _R	-	-	0.5	mA		
Forward voltage drop	I _F = 28A	V _F	-	1.67	-	٧		
Dynamic Characteristics								
Total capacitive charge	$V_R = 600V$, $I_F = 30A$ di/dt = -150A/ μ s	Qc	=	65	-	nC		



Package Outline Drawing





Disclaimer

These specifications may not be considered as a guarantee of components characteristics. Components have to be tested depending on intended application as adjustments may be necessary. The use of **iQXPRZ Power Inc.** components in life support appliances and systems are subject to written approval of **iQXPRZ Power Inc.**

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